WEST Search History

Hide Items Restore Clear Cancel

DATE: Saturday, November 12, 2005

Hide? Set Name Query						
DB=PGPB,USPT; PLUR=NO; OP=ADJ						
	L28	(L15 or L23 or nop or noop or no-op) same reorder buffer\$1	2			
$DB=EPAB,JPAB,DWPI,TDBD;\ PLUR=NO;\ OP=ADJ$						
	L27	(L19 or L26 or nop or noop or no-op) and reorder buffer\$1	0			
	L26	("no operation" or "no-operation")	1655			
DB=PGPB,USPT; PLUR=NO; OP=ADJ						
	L25	(L19 or L23 or nop or no-op) same reorder buffer\$1 2				
	L24	(L19 or L23 or nop or no-op) with reorder buffer\$1				
	L23	("no operation" or "no-operation") 11441				
	L22	nop with compress\$3	48			
$DB=EPAB,JPAB,DWPI,TDBD;\ PLUR=NO;\ OP=ADJ$						
	L21	nop with compress\$3	8			
, D	L20	L19 adj (flag\$1 or indicator\$1)	0			
	L19	"non operation" or "non-operation"	3781			
	L18	("no operation" or "no-operation") adj (flag\$1 or indicator\$1)	0			
	DB=PG	PB,USPT; PLUR=NO; OP=ADJ				
	L17	("no operation" or "no-operation") adj (flag\$1 or indicator\$1)	6			
. 🗖	L16	L15 adj (flag\$1 or indicator\$1)	6			
	L15	"non operation" or "non-operation"	3949			
	L14	buffer\$1 with L13	9			
	L13	nop with flag\$1	139			
	L12	nop with indicator\$1	15			
DB=EPAB,JPAB,DWPI,TDBD; PLUR=NO; OP=ADJ						
	L11	nop with indicator\$1	2			
	L10	nop with flag\$1	11			
\Box	L9	L7 or L8	3			
	L8	nop indicator\$1	1			
	L7	nop flag\$1	2			
DB=PGPB,USPT; PLUR=NO; OP=ADJ						
	L6	nop flag\$1	18			
	L5	nop indicator\$1	2			
	L4	fold\$3 with nop	9			

\square	L3	11 with L2	148
	L2	onchip or on-chip	28153
	Ll	dram with cache	4143

END OF SEARCH HISTORY



Search Result - Print Format

< Back t

Key: IEEE JNL = IEEE Journal or Magazine, IEE JNL = IEE Journal or Magazine, IEEE CNF = IEEE Conference, II CNF = IEE Conference, IEEE STD = IEEE Standard

1. The cache DRAM architecture: a DRAM with an on-chip cache memory

Hidaka, H.; Matsuda, Y.; Asakura, M.; Fujishima, K.; Micro, IEEE Volume 10, Issue 2, April 1990 Page(s):14 - 25 IEEE JNL

2. An experimental 1-Mbit cache DRAM with ECC

Asakura, M.; Matsuda, Y.; Hidaka, H.; Tanaka, Y.; Fujishima, K.; Solid-State Circuits, IEEE Journal of Volume 25, Issue 1, Feb. 1990 Page(s):5 - 10 IEEE JNL

3. A circuit design of intelligent cache DRAM with automatic write-back capability

Arimoto, K.; Asakura, M.; Hidaka, H.; Matsuda, Y.; Fujishama, K.; Solid-State Circuits, IEEE Journal of Volume 26, Issue 4, April 1991 Page(s):560 - 565 IEEE JNL

An eyperimental 1Mb cache DRAM with ECC

Asakura, M.; Matsuda, Y.; Hidaka, H.; Tanaka, Y.; Fujishima, K.; Yoshihara, T.; VLSI Circuits, 1989. Digest of Technical Papers., 1989 Symposium on 1989 Page(s):43 - 44 IEEE CNF

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